A M odel for N onequilibrium W etting Transitions in Two D im ensions

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A simple two dimensional (2d) model of a phase growing on a substrate is introduced. The model is characterized by an adsorption rate q, and a desorption rate p. It exhibits a wetting transition which m ay be viewed as an unbinding transition of an interface from a wall. For p = 1, the model m ay be m apped onto an exactly soluble equilibrium modelexhibiting complete wetting with critical exponents = 1=3 for the diverging interface width and $x_0 = 1$ for the zero-kevel occupation. For 0 a crossover to di erent exponents is observed which is related to a K PZ type nonlinearity.

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The interaction of a bulk phase () of a system with a wallor a substrate m ay result in very interesting wetting phenom ena. In particular a layer of a second phase (), which is preferentially attracted to the wall may be form ed in its vicinity. As som e of the param eters controlling the system , say tem perature or chem ical potential, are varied, the thickness of the layer m ay diverge, leading to a wetting transition. Such transitions have been theoretically studied and experimentally observed in a variety of system s and m odels in therm alequilibrium (for a review , see R ef. [1]). W etting transitionsm ay be view ed as the unbinding of an interface from a wall. W ithin this approach one considers the interface con guration h (r) which gives the height of the interface above the wall at point r. O ne then introduces an e ective H am iltonian of the form [2]

$$H = d^{d-1}r[\frac{1}{2}(rh)^{2} + V(h(r))]; \qquad (1)$$

is the surface tension of the - interface, where V (h (r)) yields the e ective interaction between the wall and the interface, and d 1 is the interface dimension. The potentialV which contains an attractive component m ay bind the interface to the wall. However, as the tem perature or other parameters describing the system are varied, the attractive component of the potentialm ay becom e weaker and it is no longer able to bind the interface, leading to a wetting transition. In $d = 2 \dim$ ensions one usually distinguishes between critical wetting and com plete wetting. Critical wetting is marked by the divergence of the interface width when the tem perature T is increased towards the transition temperature T_W moving along the coexistence curve of the and phases. On the other hand complete wetting is characterized by the divergence of the interface width when the chem icalpotentialdi erence between the two phases is varied, m oving tow ards the coexistence curve at T > T_W . These types of transitions are associated with two di erent sets of critical exponents.

A very interesting question which has not been studied in detail so far is that of wetting transitions under nonequilibrium conditions. Here the phase is adsorbed to the wallvia a grow th process whose dynam ics, unlike that of equilibrium processes, does not obey detailed balance. This problem may be studied by considering the behavior of a moving interface interacting with a wall. Such transitions have been reported in recent studies of the dynam ics of certain models of coupled maps [3].

In this Letter we introduce a class of nonequilibrium grow th m odels of a one dimensional interface interacting with a substrate. The interface evolves by both adsorption and desorption processes which in general do not satisfy detailed balance. By varying the relative rates of these processes, a transition from a binding to a nonbinding phase is found. For a particular value of the desorption rate, for which the dynam ics happens to have detailed balance, the m odel m ay be m apped onto an exactly soluble equilibrium m odel which exhibits a com – plete wetting unbinding transition. The associated critical exponents are = 1=3 for the interface width and $x_0 = 1$ for the base level occupation. For generic values of the desorption rate, how ever, detailed balance is violated and a crossover to di erent exponents is observed.

A. De nition of the model: The model is de ned in terms of growth of a 1d interface, in which both adsorption and desorption processes take place. We consider a restricted solid-on-solid (R SO S) growth process, where the height di erences between neighboring sites are restricted to take values 0; 1. The model is de ned on a 1d lattice of N sites with associated height variables $h_i = 0;1;::;1$ and periodic boundary conditions. We use random sequential dynamics which are de ned through the following algorithm: at each update choose a site i at random and attempt to carry out one of the processes

-adsorption of an adatom with probability q=(q+p+1):

$$h_i ! h_i + 1$$
 (2)

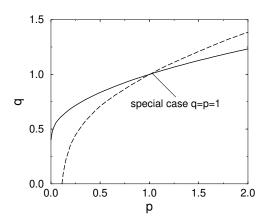


FIG.1. Phase diagram for an in nite system. The wetting transition takes place along the solid line. A long the dashed line the growth velocity in the model without a wall does not depend on a global tilt of the interface, indicating that the e ective KPZ nonlinearity vanishes. Both lines intersect in the point q = p = 1, where the m icroscopic processes obey detailed balance.

-desorption of an adatom from the edge of an island with probability 1=(q+p+1):

$$h_{i}! m in (h_{i}_{1}; h_{i}; h_{i+1})$$
 (3)

-desorption of an adatom from the interior of an island with probability p=(q + p + 1):

$$h_i ! h_i 1 \text{ if } h_{i-1} = h_i = h_{i+1}$$
 (4)

If the selected process would result in a violation of the RSOS constraint $h_i \quad h_{i+1}j \quad 1$, the attempted move is abandoned and a new site i is selected. In addition, a hard-core wall at zero height is introduced, i.e. a process is only carried out if the resulting interface heights are non-negative. One can prove that these processes in general do not satisfy detailed balance.

The presence of a hard-core wall at h = 0 leads to a phase transition that takes place even in nite systems. This can be seen as follows. W ithout the wall the interface in a nite system has a nite width. For xed p > 0 the parameter g controls the mean grow th velocity of the interface, i.e. for large q the interface grow s w hile for smallq it moves downwards. These two regimes are separated by a critical growth rate $q = q_c$ for which the m ean velocity is zero. Therefore, on large time scales, a lower wall will only a ect the interface dynam ics if the interface does not move away from the wall, i.e. q q., resulting in a smooth interface. In the growing phase $q > q_c$, however, the interface does not feel the wall. It is rough and propagates with a constant mean velocity. The phase transition line for an in nite system is shown in Fig.1.

Throughout this paper we are particularly interested in the the mean grow th velocity v in the growing phase, the occupation $_0$ of the zero-height layer in the sm ooth phase, and the interface width in the sm ooth phase which is de ned by

$$w^{2} = \frac{1}{N} \frac{X^{N}}{\prod_{i=1}^{M} h_{i}} + \frac{1}{N} \frac{X^{N}}{\prod_{j=1}^{M} h_{j}} + \frac{2}{N}$$
(5)

Consider now the thermodynamic limit N $\ !$ 1 . Near criticality in the growing phase $q>q_c$, we expect the interface velocity to scale like

$$v (q q_c)^{\gamma};$$
 (6)

whereas in the sm ooth phase, $q < q_c$, the expected scaling for bottom layer occupation and width is

0

$$(q_{c} q)^{x_{0}}; w (q_{c} q) : (7)$$

It would be interesting to nd out how the critical exponents y_{1} , x_{0} , and depend on p. W e note that the case p = 0 is special: In this case atom s cannot be desorbed from a completed layer, and the interface cannot move below its actual minimum height. This means that the hard-core wall becom es irrelevant. Therefore, the phase transition (which still exists for p = 0) relies on a com pletely di erent m echanism . The p = 0 transition is expected to belong to the universality class of a closely related model previously considered in Ref. [4]. It has been shown that in this case som e of the critical exponents can be related to the universality class of directed percolation (DP). In particular one expects $x_0 = and y = 2$, where = 0.276 and $_{?}$ = 1.73 are the density and correlation length exponents, respectively, of DP. Here completed layers play the role of absorbing states from where the system cannot escape. For p > 0, how ever, the system is ergodic and one expects di erent critical exponents. Another special case is p = 1: here the system does satisfy detailed balance and can be solved exactly. In the following, we present our analysis of the wetting transition for p = 1. We then consider the general case for which the model does not have detailed balance.

B.Exactly soluble case, p = 1: We rst show that in this case the steady state satis es detailed balance and that for q < 1 the probability of nding the interface in a particular con guration $_{H} = fh_{1}; :::;h_{N}$ g is given by the distribution

$$P(h_1;...;h_N) = P(H_H) = Z_N^{-1} q^{H(h_1;...;h_N)};$$
(8)

where

$$H = H (h_1; :::; h_N) = h_1$$
(9)

is the sum of all heights. Here, the partition sum $Z_N = P_{h_1,\dots,h_N} q^H$ runs over all interface con gurations which respect the RSOS and the hard-core wall constraints.

In order to prove Eq. (8), notice that the processes (2) { (4) subjected to the RSOS constraint correspond to a change of H by one unit. Therefore, if the distribution of Eq. (8) is to hold in the steady state, the probabilities of nding the interface in states with total height H and H + 1 have to satisfy

$$P(_{H+1})=P(_{H}) = q:$$
 (10)

As one can read of from the processes (2) { (4), any allowed transition $_{\rm H}$! $_{\rm H\,+\,1}$ occurs with rate w ($_{\rm H}$!

 $_{H+1}$) = q. M oreover, for each such process $_{H}$! $_{H+1}$, there is a reverse process $_{H+1}$! $_{H}$ which takes place with a nonzero rate. For p = 1, this rate is given by w ($_{H+1}$! $_{H}$) = 1 so that

$$w(_{H} ! _{H+1}) = w(_{H+1} ! _{H}) = q:$$
 (p = 1) (11)

Together with Eq. (10) this implies that the processes (2){ (4) satisfy detailed balance. Notice that the above consideration is consistent with the hard wall constraint h_i 0. Equation (8) yields the steady state distribution only for q < 1. The unbinding transition takes place at q = 1 and the height distribution becomes time dependent for q > 1. For $p \in 1$, detailed balance is violated. This can be proven by construction of explicit cycles of con gurations in sm all systems for which the rates of m oving clockw ise and counter-clockw ise are unequal.

We now apply the transfer matrix formalism [5,6] to study the distribution (8). Let us de ne a transfer matrix T acting in spatial direction by

$$T_{h;h^0} = \begin{array}{cc} q^h & \text{if } j_h & h^0 j & 1 \\ 0 & \text{otherw ise} \end{array} ; \qquad (12)$$

where $h;h^0$ 0. Steady state properties can be derived from the eigenvector that corresponds to the largest eigenvalue of the transfer matrix $\begin{bmatrix} 1 \\ h^0 = 0 \end{bmatrix} T_{h;h^0 = h^0} T_{h;h^0 = h^0}$

 $_{\rm h}$. From the squares of the eigenvector components one can derive various steady state quantities. For example, the probability $_{\rm h}$ of nding the interface at height h is given by $_{\rm h}$ = $^2_{\rm h}$ = $^2_{\rm h^0}$ $^2_{\rm h^0}$. Here we are particularly interested in the scaling behavior of bottom layer occupation $_0$ and the width w² = $^{}_{\rm h}$ (h h)² h, where h = $^{}_{\rm h}$ h h denotes the mean height.

C bese to criticality, where = 1 q is small, one can carry out the continuum limit $_{\rm h}$! (ñ), replacing the discrete heights h by real-valued heights ñ. Then, the above eigenvalue problem turns into a di erential equation [5] which, to leading order in , is given by

$$\frac{\theta^2}{\theta \tilde{h}^2}$$
 + (3) 3 \tilde{h} (\tilde{h}) = 0: (13)

This equation, together with the boundary conditions (0) = (1) = 0, has a unique physical solution. Sim – ple dimensional analysis indicates that the height variables scale as h $1^{=3}$ and thus the width diverges

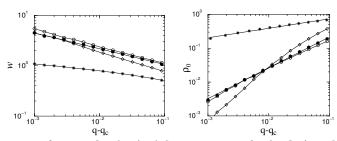


FIG.2. Results obtained from M onte C arb simulation of the growth m odel with 1500 sites. The width w and the bottom layer occupation $_0$ are measured for (?) p= 0, () p= 0.05, () p= 1, and () p= 2.0. For p= 1 we tted straight lines. The curvature for p \leq 1 indicates a crossover to KPZ exponents.

as w² $^{2=3}$. The occupation of the bottom layer in the continuum limit is given by $_0 = N^{-1} ({}^0(0))^2$, where $N = d\tilde{h}^2(\tilde{h})$ is a normalization factor. Since $^0(0)$ $^{1=3}$ and $N^{-1=3}$ one obtains a linear scaling law $_0$. The critical exponents for p = 1 are thus given by

$$x_0 = 1; = 1=3:$$
 (14)

C.Numerical results: In order to determ ine the critical exponents for other values of the grow th rate p, we perform M onte-C arlo simulations. The width w and the occupation of the bottom layer $_0$ are measured in the smooth phase $q < q_c$. Depending on $= q_c - q_c$, we rst equilibrate a system of size 1500 over a time interval up to 4 10^6 time steps. Then the therm all averages of w and $_0$ are measured over a time interval of the same size. Similarly, the interface velocity v is measured in the growing phase $q > q_c$.

The num erical data m easured in the sm ooth phase are shown in Fig. 2. From the slopes in the double logarithm ic plots we estim ate the critical exponents (see Table I). For p = 1, the num erical results we obtain are consistent with the exact values derived above. In addition the velocity exponent is found to be y = 1.01(3). For 0 we observe a crossover to di erent criticalexponents. Since the values di er from those in Eq. (14) by less than 30% and the crossover is extrem ely slow, it is di cult to determ ine these exponents precisely. Our estimates are y = 1:00(3), $x_0 = 1:5(1)$, and = 0:41(3). Sim ilar results are obtained for p > 1 except for x_0 which is close to one in this case. Finally, for p! 0, we observe another crossover. This is consistent with the results of Ref. [4] which indicate that the interface width diverges $\log arithm ically at the p = 0 transition.$

D.GeneralConsiderations: Equilibrium wetting of a 2d Ising system has been studied in Refs. [7,5]. It was shown that a column of weak bonds (which acts as an attractive potential for the domain wall separating the up and down states) located at the boundary induces a wetting transition at some nite temperature T_W . At

	p= 0	p= 0:05	p= 1:0	p= 2:0
$\mathbf{q}_{\!\mathrm{c}}$	0:3991(5)	0:5564(2)	0:9999(2)	1:2329(5)
\mathbf{x}_0	0:27(1)	1:51(6)	0 : 96 (5)	1:02(5)
	0 (log.)	0:41(3)	0:32(3)	0:37(3)
У	1 : 69(5)	0 : 98 (3)	1:01(3)	1:00(3)

TABLE I. Estim ates for the critical exponents.

the critical wetting transition the interface width diverges with = 1.

The transition found for p = 1 is of di erent nature. In this case, (1 q) acts as a chem ical potential di erence between the two coexisting phases. For q < 1 the chem ical potential di erence drives the interface tow ards the wall, resulting in a smooth interface. On the other hand, for q > 1 the interface is driven away from the wall, resulting in a KPZ-like rough moving interface [8]. The critical behavior associated with the transition is thus that of com plete wetting.

For $p \in 1$, the mapping to equilibrium is impossible since detailed balance is violated. Here a KPZ-type nonlinearity is expected to be responsible for the di erent exponents we observe. W ithin this approach, one describes the system by the Langevin equation

$$\frac{(\theta h (r;t))}{(\theta t)} = v_0 + r^2 h (r;t) \frac{(\theta V (h (r;t)))}{(\theta h (r;t))}$$
(15)
+ (r h (r;t))² + (r;t);

where (r;t) is a zero-average G aussian noise eld with variance h (r;t) $(f^{2};t^{0})i = 2D^{d-1} (r r^{0})$ $(t t^{0})$ and V is the e ective interaction between the walland the interface. This equation has been studied recently [9,10] in the context of nonlinear di usion with multiplicative noise. A simple scaling argument suggests that the width exponent corresponding to the wetting transition described by this equation is given by

$$= (2 z) = (2z 2);$$
 (16)

where z is the dynamic exponent. For a 1d interface z = 3=2, yielding = 1=2. Our num erical results indicate that the width exponent is larger for $p \in 1$ as compared with its 1=3 value at p = 1, although it seems to be smaller than 1=2. How ever, in view of the very slow crossover expected in this problem (see below) it is possible that is indeed 1=2, but more extensive simulations close to q_c would be needed to observe it.

The bottom layer occupation $_0$ m ay be related to 1 , where is the correlation length. Thus, we expect x_0 to be equal to the correlation length exponent , which for the KPZ equation is given by = 1=(2z 2), yielding $x_0 = 1$ in 1d. However, the num erical results suggest that this scaling argument is valid only for p > 1, whereas for $0 much larger values for <math>x_0$ are obtained. This may be related to the existence of di erent universality classes in both cases, corresponding to the distinction between an 'upper' and a 'lower' wall in Ref. [10].

In order to verify this picture we made a numerical estim ate of the elective nonlinear KPZ term corresponding to the RSOS model considered in this work. This is done by comparing the growth velocities of a lat and a tilted interface in absence of a wall. We not that the nonlinearity is indeed non vanishing in the (p;q) plane, except on a particular line (the dashed line in Fig.1). As expected, this line and the phase transition line are dimension the transition line the nonlinear term is not vanishing, and the KPZ-like exponents are expected to be valid. Since

is small in the vicinity of the q = p = 1 point, very slow crossover phenom ena occur, making it di cult to observe the true exponents in this region. M oreover, the interaction between the wall and the interface strongly depends on the sign of . This may lead to to di erent exponents x_0 for the bottom layer occupation on the two sides of the special point.

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- S.D ietrich, in "Phase Transitions and CriticalPhenom ena", (C.Domb and J.L.Lebowitz, eds.), Vol. 12, p.1. A cadem ic Press, London and Orlando.
- [2] D. S. Fisher and D. A. Huze, Phys. Rev. B 32, 247 (1985); D. M. Kroll and R. Lipowsky, Phys. Rev. B 26, 5289 (1982); E. Brezin, B. I. Halperin, and A. Leibler, Phys. Rev. Lett. 50, 1387 (1983).
- [3] R.Kapral, R.Livi, R.Oppo, and A.Politi, Phys. Rev.
 E 49, 2009 (1994); A.Politi, R.Livi, R.Oppo, and R.
 Kapral, Europhys. Lett. 22, 571 (1993).
- [4] U.Alon, M.R.Evans, H.Hinrichsen, and D.Mukamel, Phys.Rev.Lett. 76, 2746 (1996).
- [5] J.M. J. van Leeuwen and H. J. Hilhorst, Physica A 107, 318 (1981).
- [6] T.W.Burkhardt, J.Phys.A 14, L63 (1981).
- [7] D.B.Abraham, Phys.Rev.Lett. 44, 1165 (1980).
- [B] M. Kardar, G. Parisi, Y L. Zhang, Phys. Rev. Lett. 56, 889 (1986)
- [9] Y. Tu, G. Grinstein and M. A. Munoz Phys. Rev. Lett. 78, 274 (1997).
- [10] M.A.Munoz and T.Hwa, (unpublished).